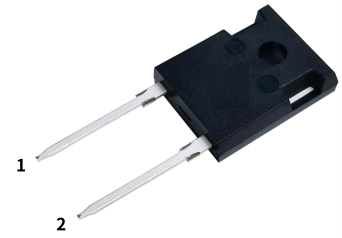
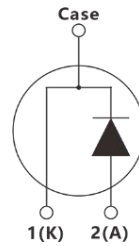


**Silicon Carbide Schottky Diode**

Parameter	Value	Unit
$V_{RRM}$	1700	V
$I_F$	20	A
$Q_C$	240	nC



TO-247-2L

**Features**

- Zero reverse recovery current
- Zero forward recovery voltage
- Temperature independent switching behavior
- High temperature operation
- High frequency operation

**Applications**

- Uninterruptible Power Supply
- Motor drives
- Photovoltaic inverters
- High-voltage DC-DC converter

**Maximum Ratings** (at  $T_J=25^\circ\text{C}$  unless otherwise specified)

Parameter	Symbol	Value	Unit
Repetitive Peak Reverse Voltage	$V_{RRM}$	1700	V
Surge Peak Reverse Voltage	$V_{RSM}$	1700	V
Continuous Forward Current $T_C=25^\circ\text{C}$ $T_C=135^\circ\text{C}$ $T_C=165^\circ\text{C}$	$I_F$	98.4 45.0 20	A
Repetitive Peak Forward Surge Current $T_C = 25^\circ\text{C}, t_p=10\text{ms}, \text{Half Sine Pulse}, D=0.1, 1000\text{Cycle}$	$I_{FRM}$	200	A
Non-Repetitive Forward Surge Current $T_C = 25^\circ\text{C}, t_p=10\text{ms}, \text{Half Sine Pulse}$	$I_{FSM}$	400	A
Non-Repetitive Forward Surge Current $T_C = 25^\circ\text{C}, t_p=10\text{ms}, \text{Half Sine Pulse}$	$\int i^2 dt$	800	A <sup>2</sup> s
Power dissipation $T_C = 25^\circ\text{C}$ $T_C = 110^\circ\text{C}$	$P_{tot}$	577 250	W
Operating junction Range	$T_j$	-55 to +175	$^\circ\text{C}$
Storage temperature Range	$T_{stg}$	-55 to +175	$^\circ\text{C}$

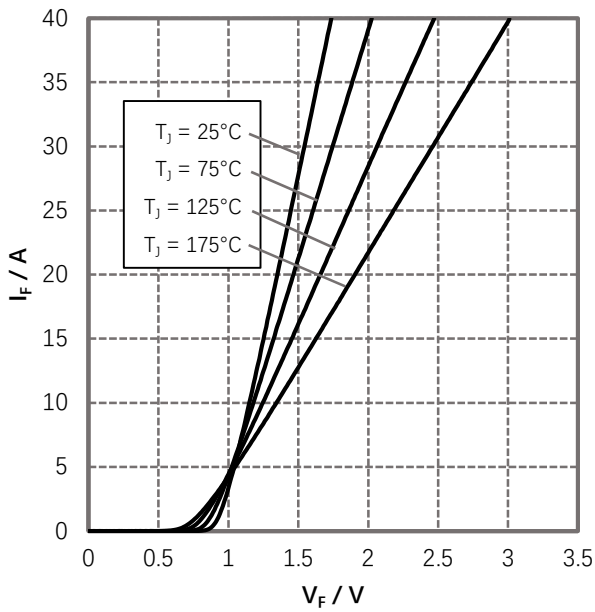
**Thermal Characteristics**

Parameter	Symbol	Typ.	Unit
Thermal resistance, junction – case.	$R_{thJC}$	0.26	$^{\circ}C/W$

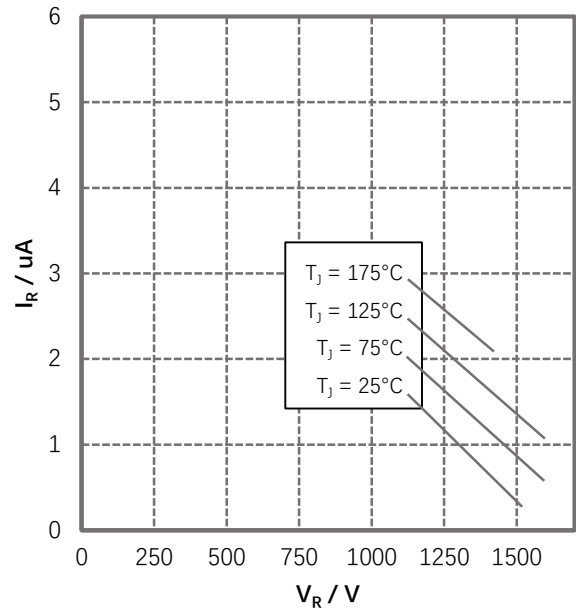
**Electrical Characteristics**(at  $T_j=25^{\circ}C$  unless otherwise specified)

Parameter	Symbol	Test conditions	Value			Unit
			Min.	Typ.	Max.	
DC blocking voltage	$V_{DC}$		1700			V
Diode forward voltage	$V_F$	$I_F=20A, T_j=25^{\circ}C$ $I_F=20A, T_j=175^{\circ}C$		1.36 1.89	1.7 2.5	V
Reverse current	$I_R$	$V_R=1700V, T_j=25^{\circ}C$ $V_R=1700V, T_j=175^{\circ}C$		0.7 5.52	100 200	$\mu A$
Total capacitive charge	$Q_C$	$V_R=1200V, T_j=25^{\circ}C$		240		nC
Total capacitance	C	$T_j=25^{\circ}C$ $V_R=0V, f=1MHz$ $V_R=400V, f=1MHz$ $V_R=800V, f=1MHz$		2800 188 136		pF
Capacitance Stored Energy	$E_C$	$V_R=1200V$	-	182	-	$\mu J$

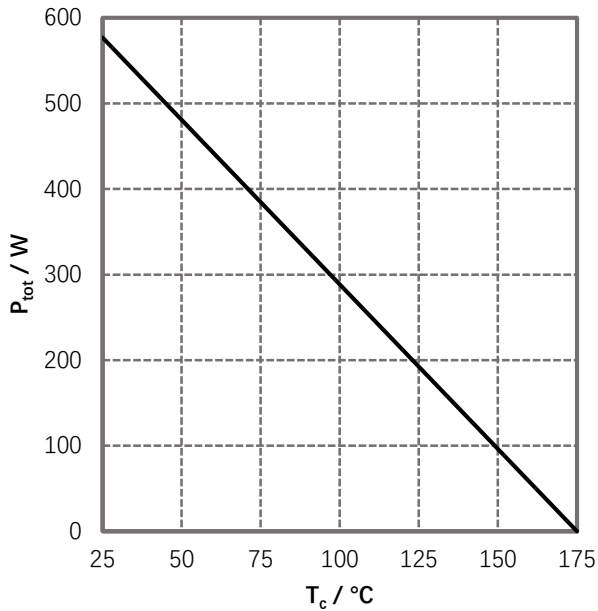
**Typical Characteristics**



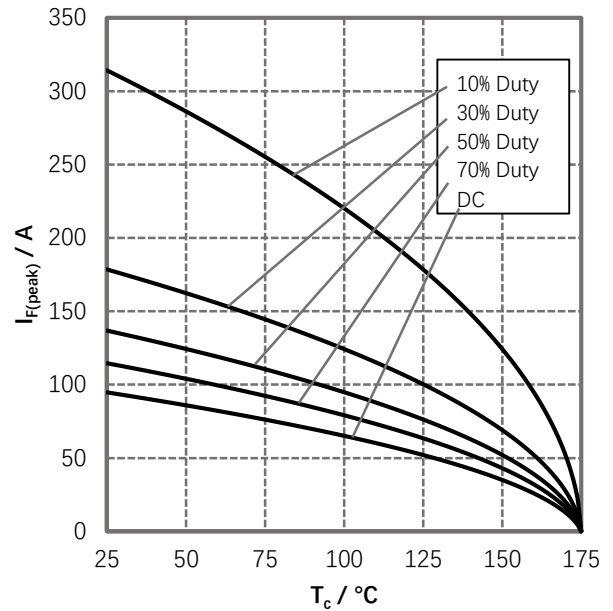
**Figure 1. Forward Characteristics**



**Figure 2. Reverse Characteristics**



**Figure 3. Power Derating**



**Figure 4. Current Derating**  
Valid for switching of above 20kHz,  
excluding D.C. curve

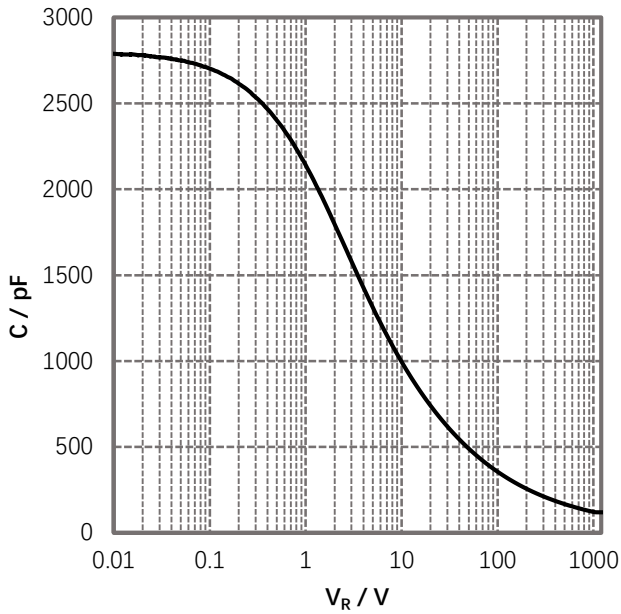


Figure 5. Capacitance vs. Reverse Voltage

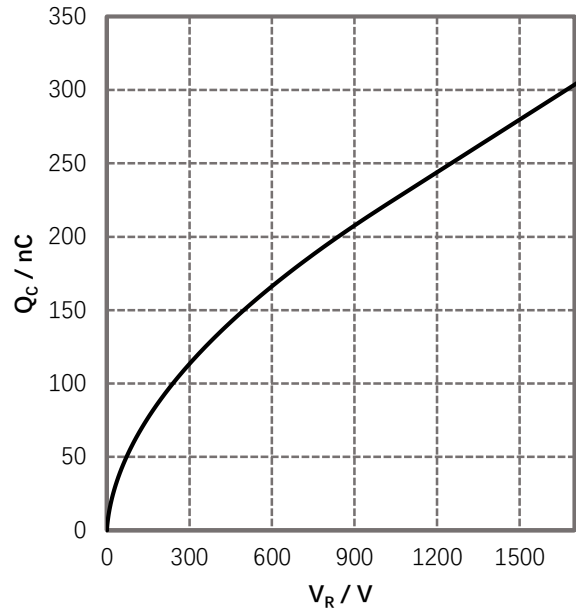


Figure 6. Reverse Charge vs. Reverse Voltage

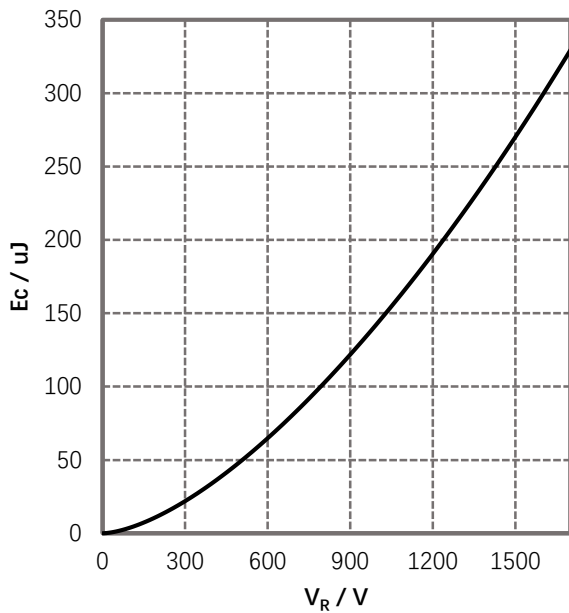


Figure 7. Capacitance Stored Energy

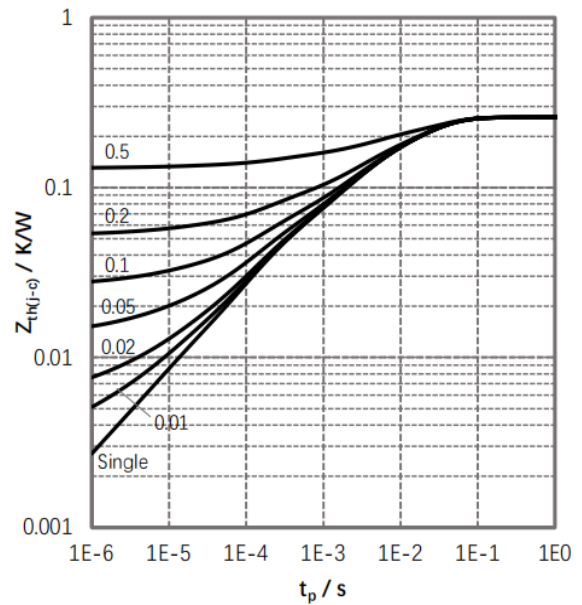
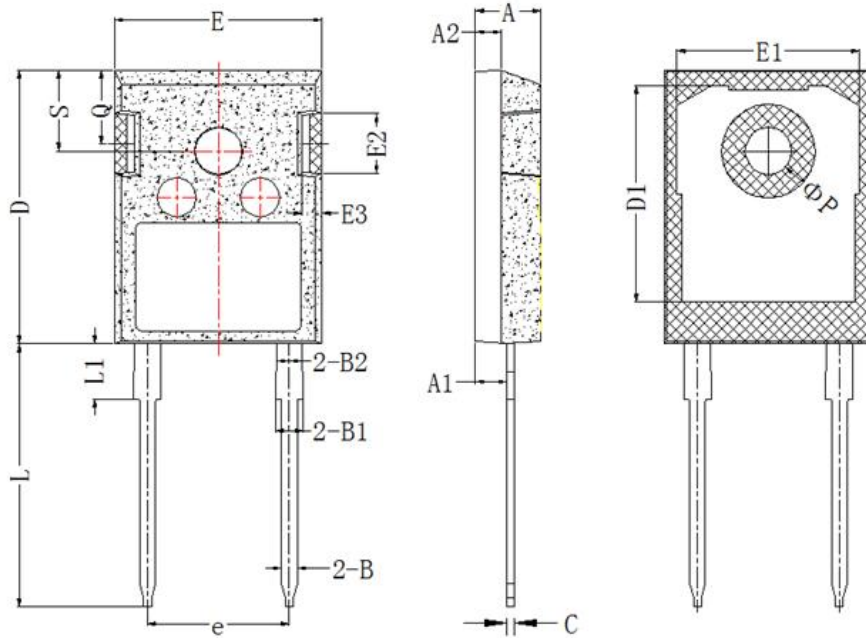


Figure 8. Transient Thermal Impedance

Package Outlines(Unit:mm)

TO-247-2L



Items	Values(mm)	
	MIN	MAX
A	4.85	5.15
A1	2.25	2.55
A2	1.85	2.15
B	1.04	1.33
B1	1.90	2.35
B2	1.90	2.15
C	0.55	0.68
D	20.80	21.10
D1	16.25	17.65
D2	0.95	1.35
E	15.70	16.10
E1	13.50	14.20
E2	3.80	5.00
E3	1.00	2.60
e	10.63	11.13
L	19.80	20.30
L1	4.00	4.50
$\phi P$	3.50	3.70
Q	5.40	6.00
S	6.00	6.40

**\*Important Usage Information and Disclaimer**

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